



CHENMKO ENTERPRISE CO.,LTD

Lead free devices

**SURFACE MOUNT
SWITCHING DIODE**

VOLTAGE 80 Volts CURRENT 100 mAmpere

CHP11NPT

APPLICATION

- * Ultra high speed switching

FEATURE

- * Small surface mounting type. (SC-88/SOT-363)
- * Multiple diodes in one small surface mount package.
- * Suitable for high packing density.
- * Maximum total power dissipation is 150*2 mW.
- * Peak forward current is 300mA.

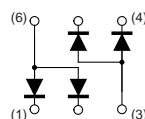
CONSTRUCTION

- * Silicon epitaxial planar

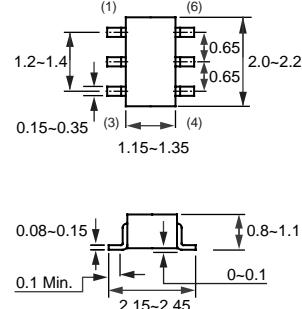
MARKING

- * DZ

CIRCUIT



SC-88/SOT-363



SC-88/SOT-363

MAXIMUM RATINGS (At TA = 25°C unless otherwise noted)

RATINGS	SYMBOL	CHP11NPT	UNITS
Maximum Recurrent Peak Reverse Voltage	VR _{RM}	80	Volts
Maximum RMS Voltage	V _{RMS}	56	Volts
Maximum DC Blocking Voltage	V _D C	80	Volts
Maximum Average Forward Rectified Current	I _O	100	mAmps
Peak Forward Surge Current at 1uSec.	I _{FSM}	4.0	Amps
Typical Junction Capacitance between Terminal (Note 1)	C _J	3.5	pF
Maximum Reverse Recovery Time (Note 2)	T _{RR}	4.0	nSec
Maximum Operating Temperature Range	T _J	+150	°C
Storage Temperature Range	T _{STG}	-55 to +150	°C

ELECTRICAL CHARACTERISTICS (At TA = 25°C unless otherwise noted)

CHARACTERISTICS	SYMBOL	CHP11NPT	UNITS
Maximum Instantaneous Forward Voltage at I _F = 100mA	V _F	1.20	Volts
Maximum Average Reverse Current at V _R = 70V	I _R	0.1	uAmps

NOTES : 1. Measured at 1.0 MHz and applied reverse voltage of 6.0 volts.
2. Measured at applied forward current of 5mA and reverse voltage of 6.0 volts.
3. ESD sensitive product handling required.

2003-5

RATING CHARACTERISTIC CURVES (CHP11NPT)

FIG. 1 - POWER DERATING CURVE

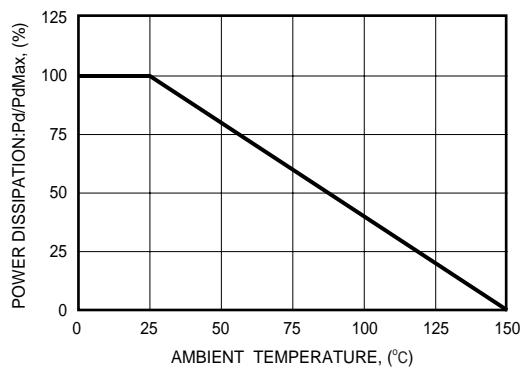


FIG. 2 - FORWARD CHARACTERISTICS

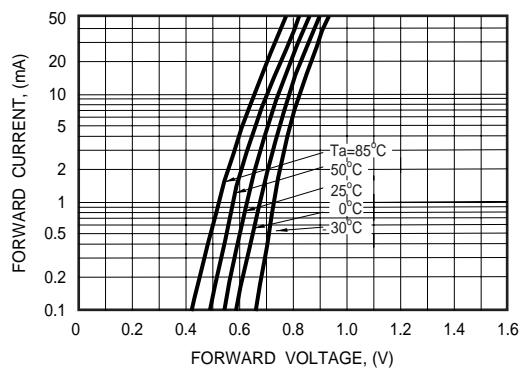


FIG. 3 - TYPICAL JUNCTION CAPACITANCE

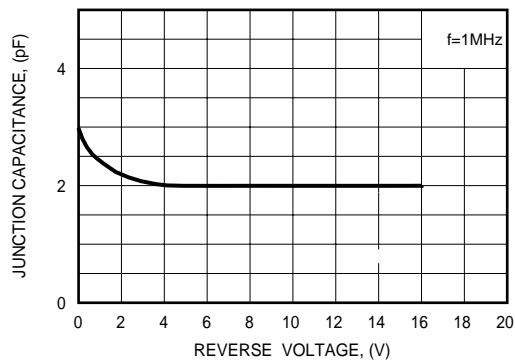


FIG. 4 - REVERSE CHARACTERISTICS

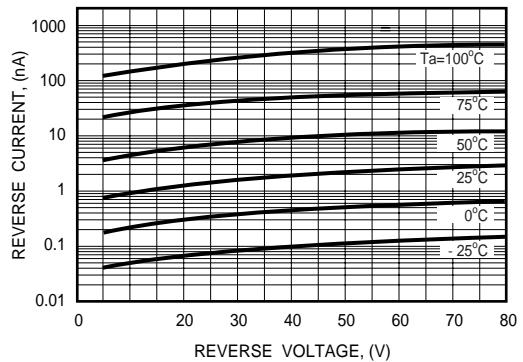


FIG. 5 - REVERSE RECOVERY TIME

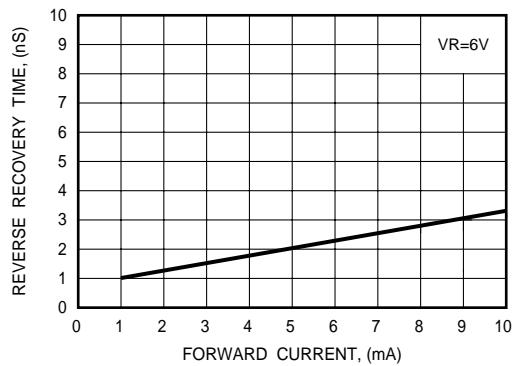


FIG. 6 - REVERSE RECOVERY TIME MEASUREMENT CIRCUIT

